

# M63812P/FP/GP/KP

## 7-UNIT 300mA TRANSISTOR ARRAY WITH CLAMP DIODE

## **DESCRIPTION**

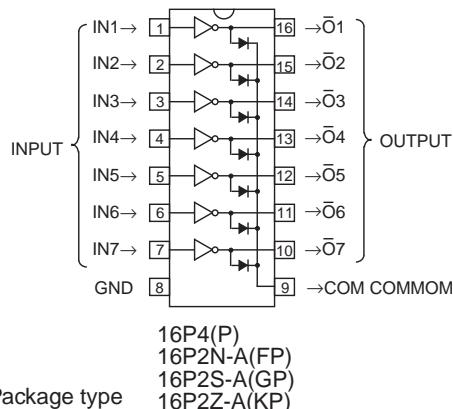
M63812P, M63812FP, M63812GP and M63812KP are seven-circuit Single transistor arrays with clamping diodes. The circuits are made of NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

## FEATURES

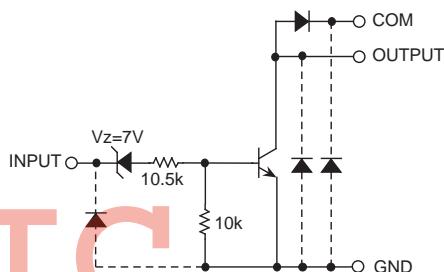
- Four package configurations (P, FP, GP and KP)
  - Medium breakdown voltage ( $BV_{CEO} \geq 35V$ )
  - Synchronizing current ( $I_{C(max)} = 300mA$ )
  - With clamping diodes
  - With zener diodes
  - Low output saturation voltage
  - Wide operating temperature range ( $T_a = -40$  to  $+85^{\circ}C$ )

## APPLICATION

Driving of digit drives of indication elements (LEDs and lamps) with small signals



## CIRCUIT DIAGRAM



The seven circuits share the COM and GND.

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit:  $\Omega$

## FUNCTION

The M63812P, M63812FP, M63812GP and M63812KP each have seven circuits consisting of NPN transistor. A spike-killer clamping diode is provided between each output pin (collector) and COM pin (pin9). The transistor emitters are all connected to the GND pin (pin 8). The transistors allow synchronous flow of 300mA collector current. A maximum of 35V voltage can be applied between the collector and emitter.

**ABSOLUTE MAXIMUM RATINGS** (Unless otherwise noted,  $T_a = -40 \sim +85^\circ\text{C}$ )

| Symbol | Parameter                      | Conditions                       | Ratings    | Unit |
|--------|--------------------------------|----------------------------------|------------|------|
| VCEO   | Collector-emitter voltage      | Output, H                        | -0.5 ~ +35 | V    |
| Ic     | Collector current              | Current per circuit output, L    | 300        | mA   |
| VI     | Input voltage                  |                                  | -0.5 ~ +35 | V    |
| IF     | Clamping diode forward current |                                  | 300        | mA   |
| VR     | Clamping diode reverse voltage |                                  | 35         | V    |
| Pd     | Power dissipation              | Ta = 25°C, when mounted on board | M63812P    | 1.47 |
|        |                                |                                  | M63812FP   | 1.00 |
|        |                                |                                  | M63812GP   | 0.80 |
|        |                                |                                  | M63812KP   | 0.78 |
|        |                                |                                  |            |      |
| Topr   | Operating temperature          |                                  | -40 ~ +85  | °C   |
| Tstg   | Storage temperature            |                                  | -55 ~ +125 | °C   |

**7-UNIT 300mA TRANSISTOR ARRAY WITH CLAMP DIODE****RECOMMENDED OPERATING CONDITIONS** (Unless otherwise noted, Ta = -40 ~ +85°C)

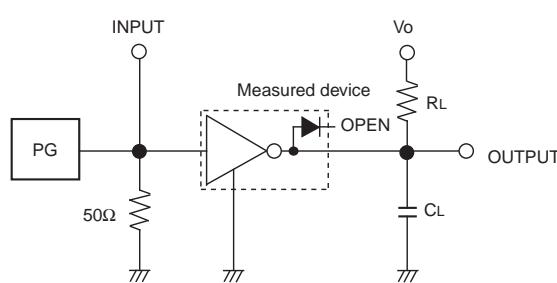
| Symbol | Parameter   | Test conditions | Limits                       |     |     | Unit |
|--------|---|-----------------|------------------------------|-----|-----|------|
|        |   |                 | min                          | typ | max |      |
| Vo     | Output voltage  |                 | 0                            | —   | 35  | V    |
| Ic     | Collector current<br>(Current per 1 circuit when 7 circuits are coming on simultaneously) | M63812P         | Duty Cycle no more than 45%  | 0   | —   | 250  |
|        |   |                 | Duty Cycle no more than 100% | 0   | —   | 160  |
|        |   | M63812FP        | Duty Cycle no more than 30%  | 0   | —   | 250  |
|        |   |                 | Duty Cycle no more than 100% | 0   | —   | 130  |
|        |   | M63812GP        | Duty Cycle no more than 24%  | 0   | —   | 250  |
|        |   |                 | Duty Cycle no more than 100% | 0   | —   | 120  |
|        |   | M63812KP        | Duty Cycle no more than 24%  | 0   | —   | 250  |
|        |   |                 | Duty Cycle no more than 100% | 0   | —   | 120  |
| VIN    | Input voltage   |                 | 0                            | —   | 30  | V    |

**ELECTRICAL CHARACTERISTICS** (Unless otherwise noted, Ta = 25°C)

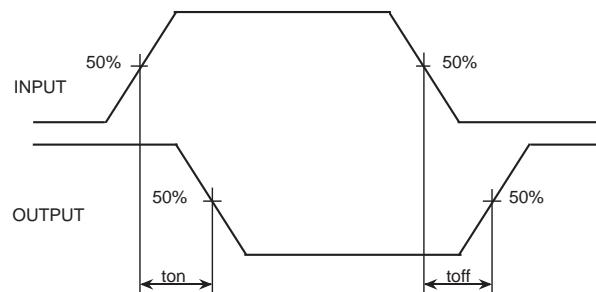
| Symbol     | Parameter                            | Test conditions       | Limits |     |     | Unit |
|------------|--------------------------------------|-----------------------|--------|-----|-----|------|
|            |                                      |                       | min    | typ | max |      |
| V (BR) CEO | Collector-emitter breakdown voltage  | ICEO = 10µA           | 35     | —   | —   | V    |
| VCE(sat)   | Collector-emitter saturation voltage | IIN = 1mA, IC = 10mA  | —      | —   | 0.2 | V    |
|            |                                      | IIN = 2mA, IC = 150mA | —      | —   | 0.8 |      |
| VIN(on)    | "On" input voltage                   | IIN = 1mA, IC = 10mA  | 13     | 19  | 23  | V    |
| VR         | Clamping diode forward voltage       | IF = 250mA            | —      | 1.2 | 2.0 | V    |
| IR         | Clamping diode reverse current       | VR = 35V              | —      | —   | 10  | µA   |
| hFE        | DC amplification factor              | VCE = 10V, IC = 10mA  | 50     | —   | —   | —    |

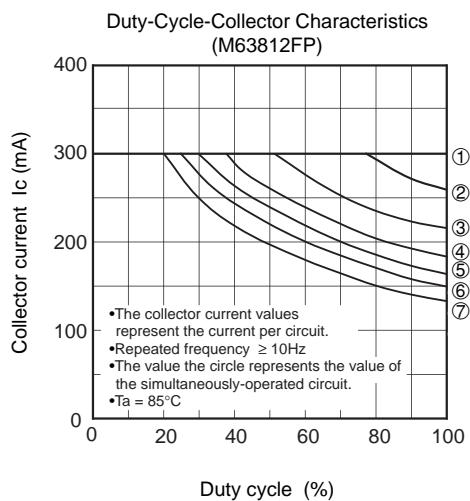
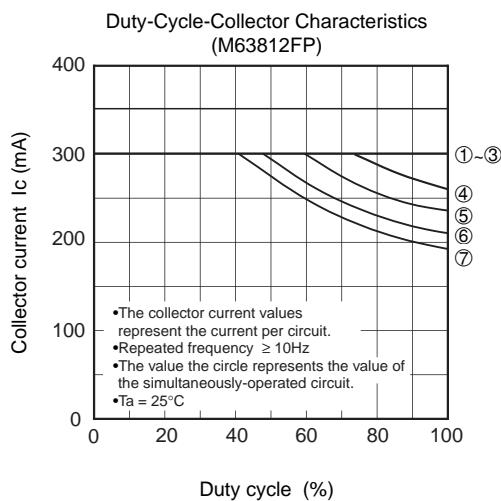
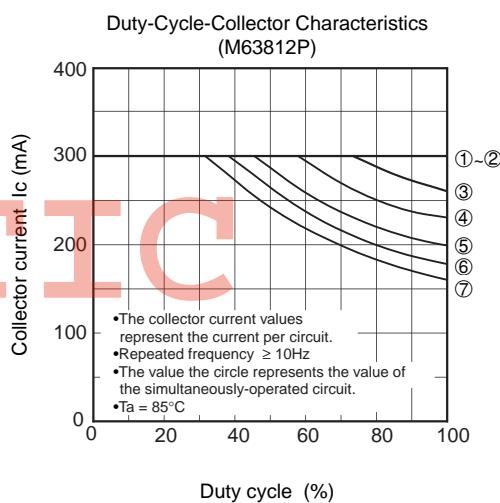
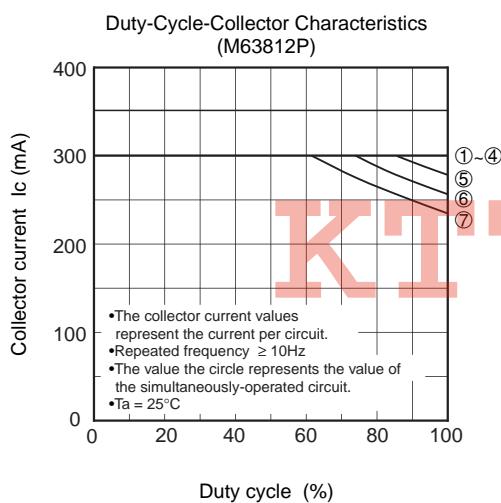
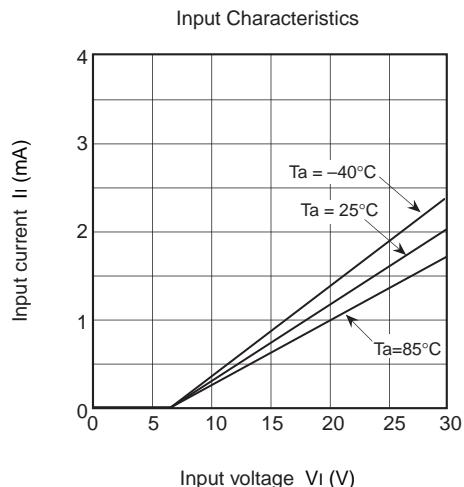
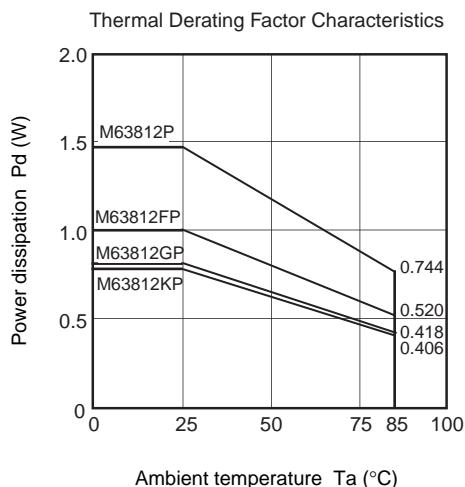
**SWITCHING CHARACTERISTICS** (Unless otherwise noted, Ta = 25°C)

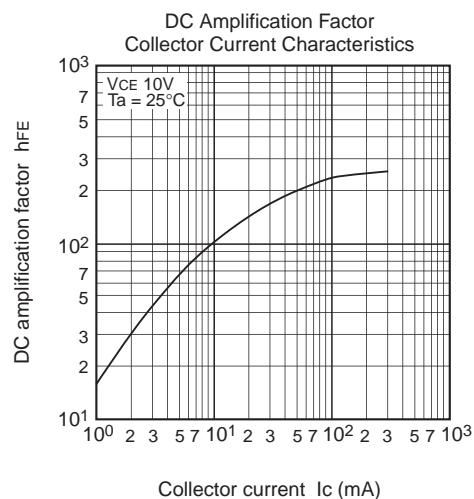
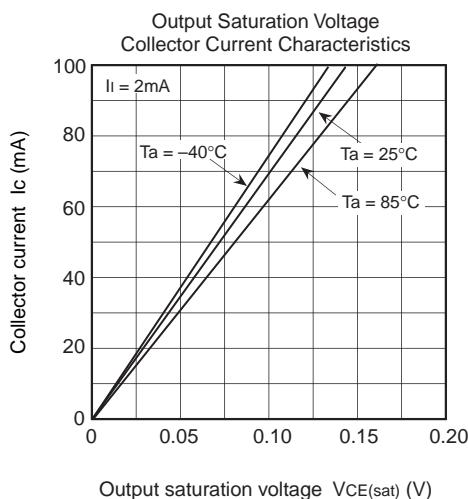
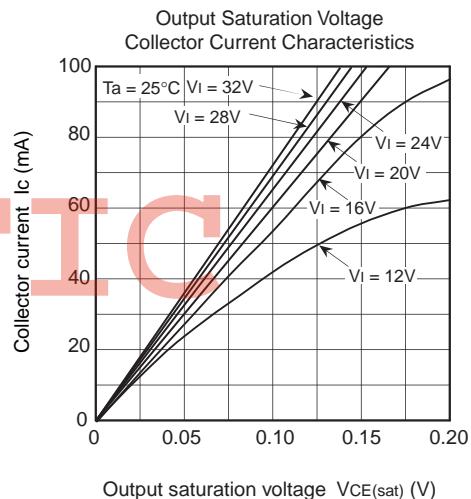
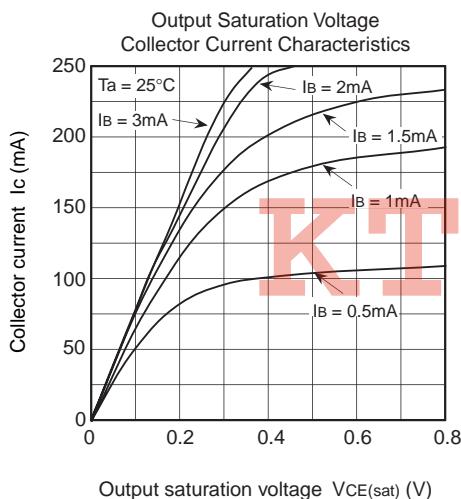
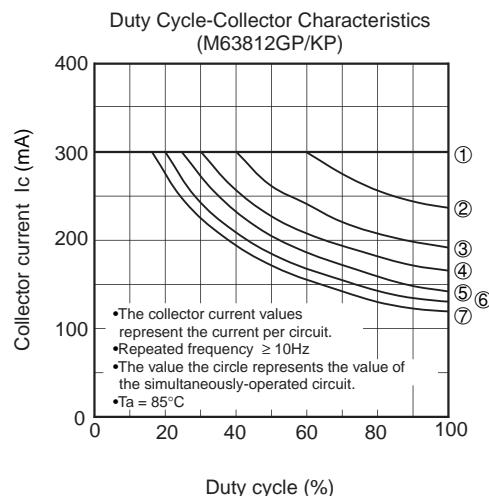
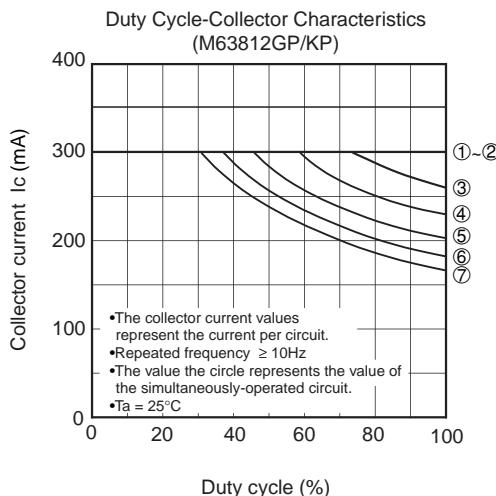
| Symbol | Parameter     | Test conditions    | Limits |     |     | Unit |
|--------|---------------|--------------------|--------|-----|-----|------|
|        |               |                    | min    | typ | max |      |
| ton    | Turn-on time  | CL = 15pF (note 1) | —      | 140 | —   | ns   |
| toff   | Turn-off time |                    | —      | 240 | —   | ns   |

**NOTE 1 TEST CIRCUIT**

- (1)Pulse generator (PG) characteristics : PRR = 1kHz,  
tw = 10µs, tr = 6ns, tf = 6ns, Zo = 50Ω, V<sub>IH</sub> = 18V  
(2)Input-output conditions : RL=220Ω, Vo=35V  
(3)Electrostatic capacity CL includes floating capacitance at connections and input capacitance at probes

**TIMING DIAGRAM**

**TYPICAL CHARACTERISTICS**

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